

Product Summary

V _{(BR)DSS}	R _{DS(on)TYP}	I _D
-20V	25mΩ@-4.5V	-5.5A
-20V	30mΩ@-2.5V	-5.5A



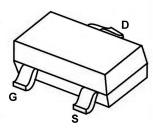
Feature

- High power and current handing capability
- Surface mount package

Application

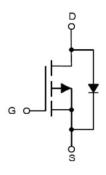
- Battery Switch
- DC/DC Converter

Package

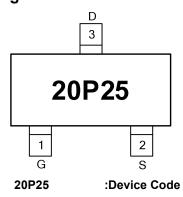


SOT-23

Circuit diagram



Marking



Order Information

Device	Package	Unit/Tape
SP20P25T2	SOT-23	3000

Absolute maximum ratings (Ta=25℃, unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	-20	V
Gate-Source Voltage	V _{GSS}	±12	V
Continuous Drain Current	I _D	-5.5	А
Pulse Drain Current Tested	I _{DM}	-22	A
Power Dissipation	P _D	1.1	W
Thermal Resistance Junction-to-Ambient	Reja	113	°C/W
Storage Temperature Range	T _{STG}	-55 to 150	°C
Operating Junction Temperature Range	TJ	-55 to 150	°C

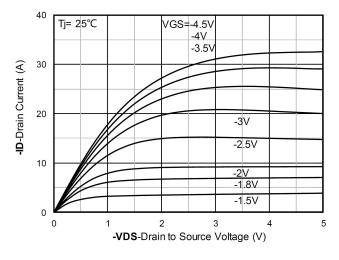
Electrical characteristics (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V , ID=-250μA	-20	-	-	V
Drain-Source Leakage Current	I _{DSS}	VDS=-16V , VGS=0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	VGS=±12V , VDS=0V	-	-	±100	nA
Gate Threshold Voltage	V _{GS(th)}	VDS=VGS , ID=-250μA	-0.4	-0.65	-1.0	V
Static Drain-Source On-Resistance	Б	VGS=-4.5V, ID=-3.5A	-	25	32	mΩ
	R _{DS(ON)}	VGS=-2.5V, ID=-3A	-	30	40	
Dynamic characteristics						•
Input Capacitance	C _{iss}		-	960	-	
Output Capacitance	Coss	VDS=-15V , VGS=0V , f=1MHz	-	127	-	pF
Reverse Transfer Capacitance	Crss		-	96	-	
Total Gate Charge	Qg		-	9.4	-	nC
Gate-Source Charge	Q _{gs}	VDS=-15V , VGS=-4.5V , ID=-3A	-	1.3	-	
Gate-Drain Charge	Q _{gd}		-	2.3	-	
Switching Characteristics						
Turn-On Delay Time	t _{d(on)}		-	9.8	-	
Turn-On Rise Time	t _r	VDD=-10V VGS=-4.5V , RG=3.3Ω, ID=3A,	-	26.2	-]
Turn-Off Delay Time	t _{d(off)}		-	48.5	-	nS
Turn-Off Fall Time	t _f		-	41.6	-	
Source-Drain Diode characteristics						
Diode Forward Voltage	V _{SD}	VGS=0V , IS=-1A , TJ=25℃	-	-	-1.2	V

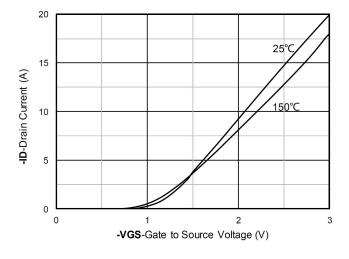
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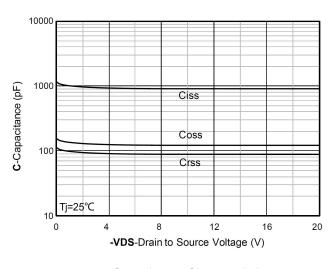
Typical Characteristics



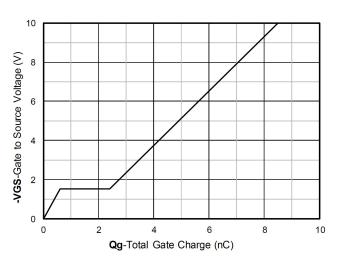




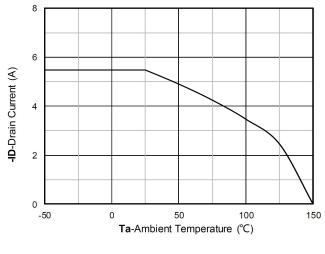
Transfer Characteristics



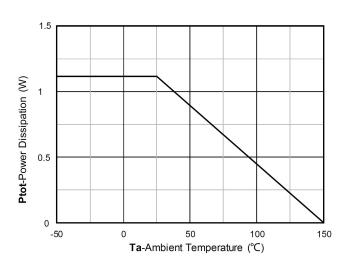
Capacitance Characteristics



Gate Charge

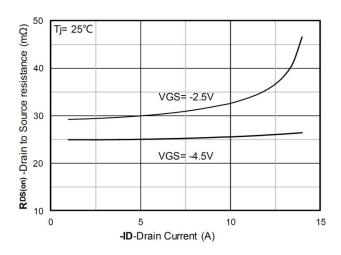


Current dissipation

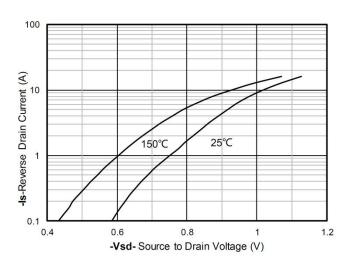


Power dissipation

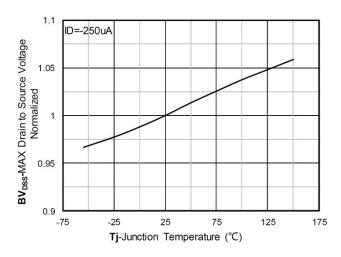




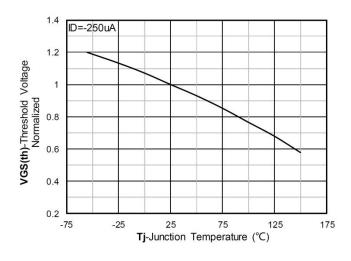
RDS(on) VS Drain Current



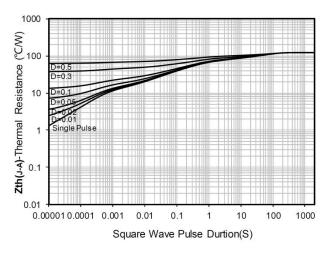
Forward characteristics of reverse diode



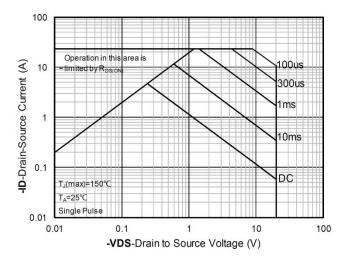
Normalized breakdown voltage



Normalized Threshold voltage

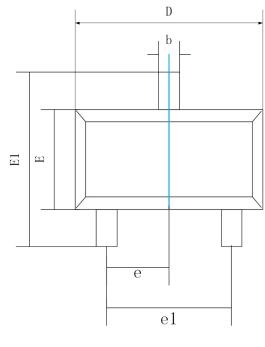


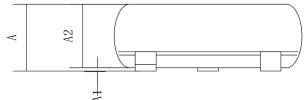
Maximum Transient Thermal Impedance

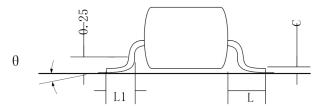


Safe Operation Area

SOT-23 Package Information







共面度0-0.09mm

Compleal	Dimensions In Millimeters		
Symbol	Min.	Max.	
A	0.90	1.15	
A1	0.00	0.10	
A2	0.90	1.05	
b	0.30	0.50	
С	0.08	0.15	
D	2.80	3.00	
E	1.20	1.40	
E1	2.25	2.55	
е	0.95 REF.		
e1	1.80	2.00	
L	0.55 REF.		
L1	0.30	0.30 0.50	
θ	0°	8°	